

#### **NPN MEDIUM POWER TRANSISTORS IN SOT89**

#### **Features**

- BV<sub>CEO</sub> > 45V, 60V & 80V
- I<sub>c</sub> = 1A Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 500mV @ 0.5A</li>
- Gain Groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary PNP Types: BCX51, 52, and 53
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BCX5616QTA is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

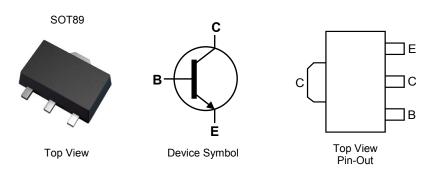
https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound;
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads.
  Solderable per MIL-STD-202 Method 208 (2)
- Weight: 0.055 grams (Approximate)

### **Applications**

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



## **Ordering Information** (Note 4)

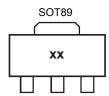
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCX54TA	Standard	BA	7	12	1,000
BCX5410TA	Standard	BC	7	12	1,000
BCX5416TA	Standard	BD	7	12	1,000
BCX5416-13R	Standard	BD	13	12	4,000
BCX55TA	Standard	BE	7	12	1,000
BCX5510TA	Standard	BG	7	12	1,000
BCX5516TA	Standard	BM	7	12	1,000
BCX56TA	Standard	BH	7	12	1,000
BCX5610TA	Standard	BK	7	12	1,000
BCX5616TA	Standard	BL	7	12	1,000
BCX5616TC	Standard	BL	13	12	4,000
BCX5410TC	Standard	BC	13	12	4,000
BCX5416TC	Standard	BD	13	12	4,000
BCX54TC	Standard	BA	13	12	4,000
BCX5510TC	Standard	BG	13	12	4,000
BCX5516TC	Standard	BM	13	12	4,000
BCX55TC	Standard	BE	13	12	4,000
BCX5610TC	Standard	BK	13	12	4,000
BCX56TC	Standard	BH	13	12	4,000
BCX5616QTA	Automotive	Refer to h	ttps://www.diodes.com/as	ssets/Datasheets/BCX5	616Q.pdf

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



xx = Product Type Marking Code, as follows:

BCX54 = BA BCX55 = BE BCX56 = BH BCX5410 = BC BCX5510 = BG BCX5610 = BK BCX5416 = BD BCX5516 = BM BCX5616 = BL

# **Absolute Maximum Ratings** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX54	BCX55	BCX56	Unit
Collector-Base Voltage	$V_{CBO}$	45	60	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	60	80	V
Emitter-Base Voltage	V <sub>EBO</sub>		6		V
Continuous Collector Current	Ic		1		۸
Peak Pulse Collector Current	I <sub>CM</sub>		2		A
Continuous Base Current	I <sub>B</sub>		100		m A
Peak Pulse Base Current	I <sub>BM</sub>		200		mA .

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	(Note 5)		1	
Power Dissipation	(Note 6)	$P_{D}$	1.5	W
	(Note 7)		2.0	
	(Note 5)		125	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	83	°C/W
	(Note 7)		60	
Thermal Resistance, Junction to Lead	(Note 8)	R <sub>0JL</sub>	13	°C/W
Thermal Resistance, Junction to Case	(Note 9)	R <sub>0JC</sub>	27	°C/W
Operating and Storage Temperature Range	•	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured

under still-air conditions whilst operating in a steady-state.

Notes:

Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.

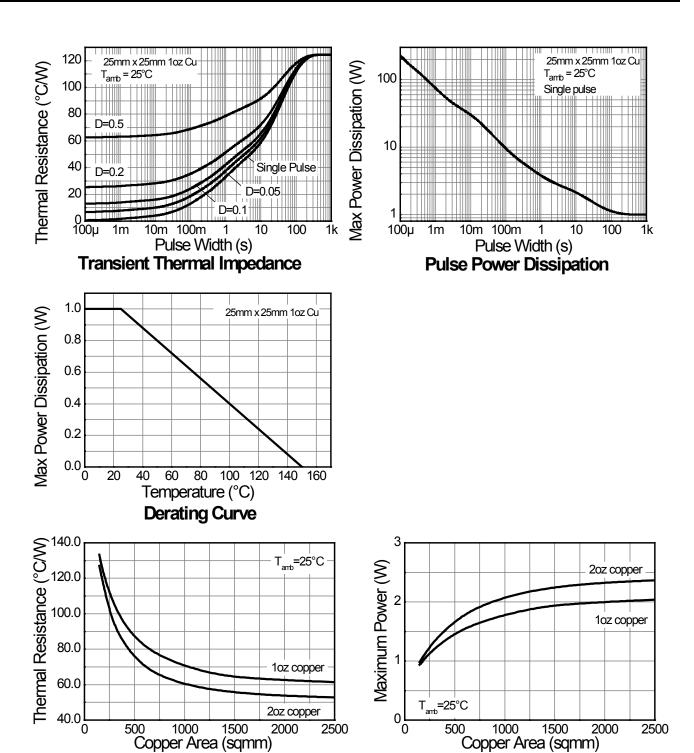
<sup>8.</sup> Thermal resistance from junction to solder-point (on the exposed collector pad).

<sup>9.</sup> Thermal resistance from junction to the top of the case.

<sup>10.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**



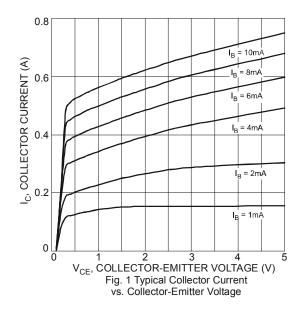


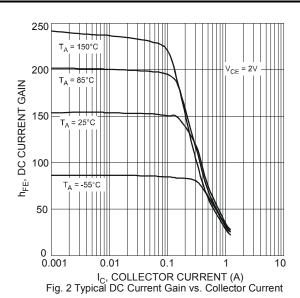
## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base	BCX54		45				
Breakdown Voltage	BCX55	$BV_CBO$	60	_	_	V	$I_{C} = 100 \mu A$
Breakdown voltage	BCX56		100				
Collector-Emitter	BCX54		45				
Breakdown Voltage (Note 11)	BCX55	BV <sub>CEO</sub>	60	_	_	V	I <sub>C</sub> = 10mA
Breakdown Voltage (Note 11)	BCX56		80				
Emitter-Base Breakdown Voltage		$BV_{EBO}$	6	_	_	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current		lone			0.1	μA	V <sub>CB</sub> = 30V
Collector Cut-On Current		I <sub>CBO</sub>		_	20	μΑ	$V_{CB} = 30V, T_A = +150^{\circ}C$
Emitter Cut-Off Current		I <sub>EBO</sub>	_	_	20	nA	V <sub>EB</sub> = 5V
			25	_	_		$I_C = 5mA$ , $V_{CE} = 2V$
	All versions		40	_	250		$I_C = 150 \text{mA}, V_{CE} = 2 \text{V}$
Static Forward Current Transfer Ratio (Note 11)		h <sub>FE</sub>	25	_	_		$I_C$ = 500mA, $V_{CE}$ = 2V
rtatio (Note 11)	10 gain grp		63	_	160		$I_C = 150 \text{mA}, V_{CE} = 2V$
	16 gain grp		100	_	250		I <sub>C</sub> = 150mA, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltag	je (Note 11)	V <sub>CE(sat)</sub>	_	_	0.5	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Base-Emitter Turn-On Voltage (No	ote 11)	V <sub>BE(on)</sub>	_	_	1.0	V	I <sub>C</sub> = 500mA, V <sub>CE</sub> = 2V
Transition Frequency		fτ	150	_	_	MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V f = 100MHz
Output Capacitance		Cobo	_	_	25	pF	V <sub>CB</sub> = 10V, f = 1MHz

Note:

# Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

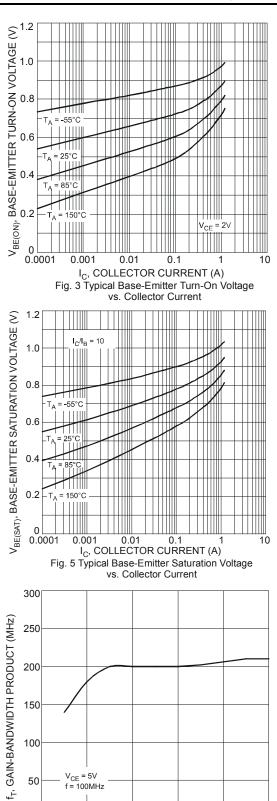




<sup>11.</sup> Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (continued)



60

I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current

40

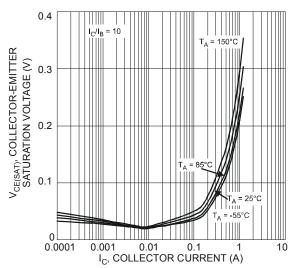


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

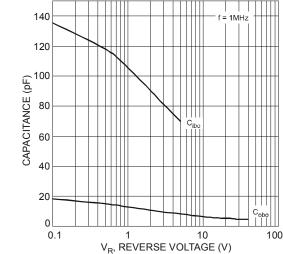


Fig. 6 Typical Capacitance Characteristics

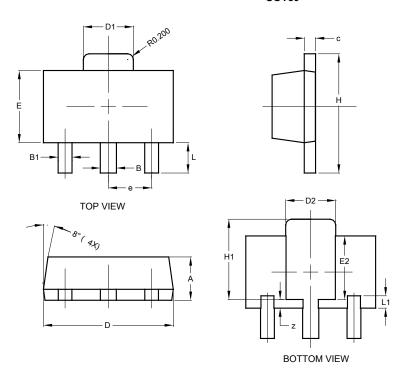
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# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT89

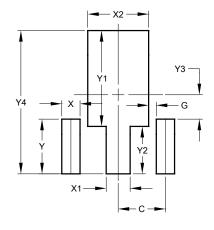


	SC	OT89	
Dim	Min	Max	Тур
A	1.40	1.60	1.50
В	0.50	0.62	0.56
B1	0.42	0.54	0.48
C	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
Е	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	ı	ı	1.50
Н	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
Z	0.20	0.40	0.30
All	Dimen	sions	in mm

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT89**



(in mm)	<b>Dimensions</b>
	Dilliensions
C 1.500	С
<b>G</b> 0.244	G
<b>X</b> 0.580	Х
<b>X1</b> 0.760	X1
<b>X2</b> 1.933	X2
Y 1.730	Y
<b>Y1</b> 3.030	Y1
<b>Y2</b> 1.500	Y2
<b>Y3</b> 0.770	Y3
<b>Y4</b> 4.530	Y4



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